Application No.: Not Yet Assigned Docket No.: M4065.0451/P451-B

AMENDMENTS TO THE CLAIMS

 (Original) A method of measuring the resistance of a memory element comprising: producing a plurality of electrical pulses at a rate related to said memory element resistance;

counting said electrical pulses over a predetermined time period to produce a pulse count; and

evaluating said pulse count to determine said resistance.

2-27. (Canceled)